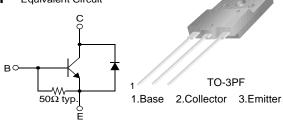


### KSD5702

High Voltage Color Display Horizontal Equivalent Circuit **Deflection Output** 

(Damper Diode Built In)

- High Collector-Base Voltage :  $V_{CBO}$ =1500V High Switching Speed  $t_F$  = 0.4 $\mu$ s (Max.)
- For Color TV



## **NPN Triple Diffused Planar Silicon Transistor**

Absolute Maximum Ratings  $\rm T_{C} = 25^{\circ}C$  unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	1500	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	800	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
I <sub>C</sub>	Collector Current	6	Α	
I <sub>CP</sub>	Collector Current (Pulse)	16	Α	
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C) Data Sheet 411 com	60	W	
TJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C	

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 800V, I_{E} = 0$			10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$	40		200	mA
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 1A$	10		30	-
h <sub>FE2</sub>		$V_{CE} = 5V, I_{C} = 3A$	5		15	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 4A, I_B = 0.8A$		2	5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 4A, I_B = 0.8A$			1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 1A$		3		MHz
V <sub>F</sub>	Damper Diode Turn On Voltage	I <sub>F</sub> = 6A			2	V
t <sub>F</sub>	Fall Time	$V_{CC} = 200V, I_C = 4A$ $I_{B1} = 0.8A, I_{B2} = -1.6A$ $R_L = 50\Omega$			0.4	μs

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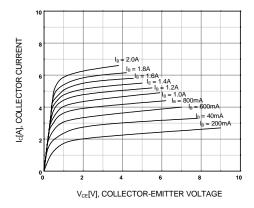


Figure 1. Static Characteristic

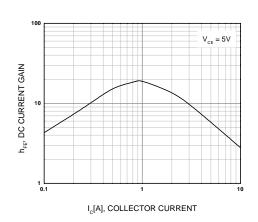


Figure 2. DC current Gain

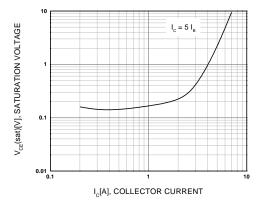


Figure 3. Collector-Emitter Saturation Voltage

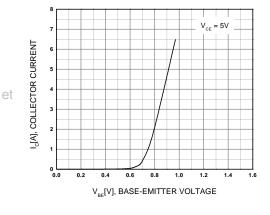


Figure 4. Base-Emitter On Voltage

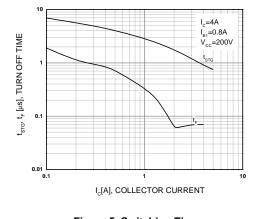


Figure 5. Switching Time

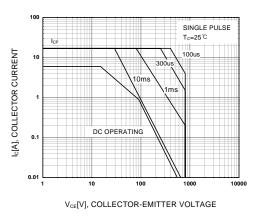
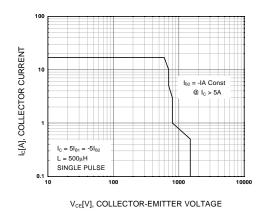


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)



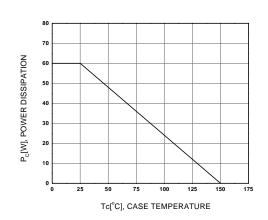


Figure 7. Reverse Bias Safe Operating Area

Figure 8. Power Derating

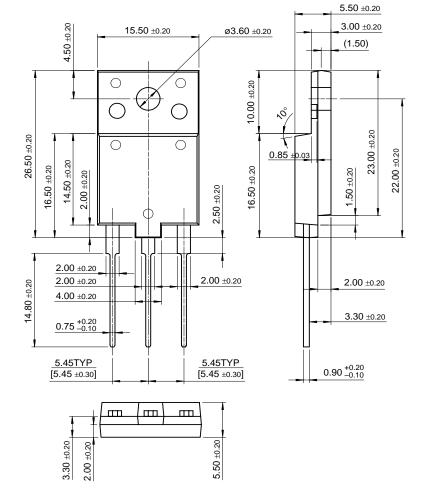
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## TO-3PF



Dimensions in Millimeters

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